

HF/VHF/UHF RF power N-channel MOSFET

Datasheet - production data

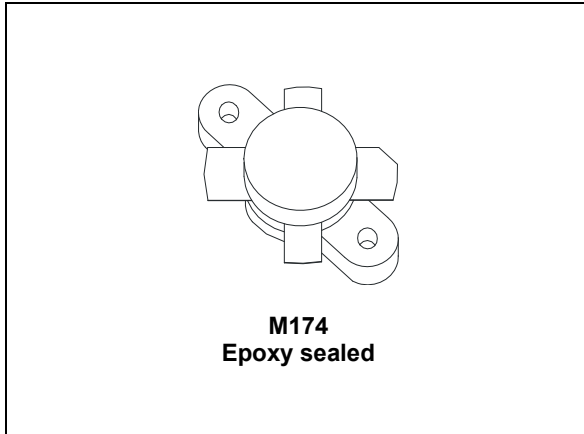
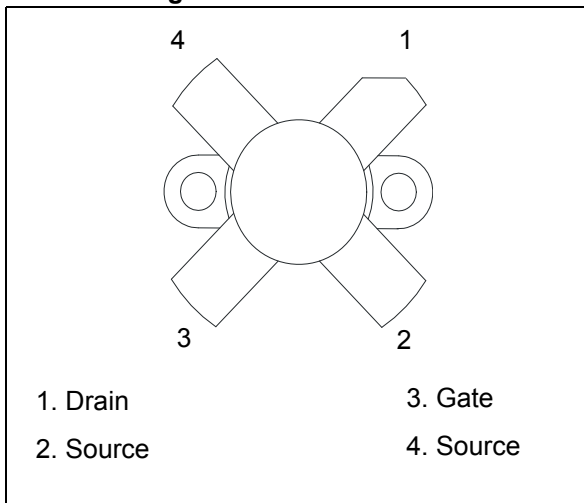


Figure 1. Pin connection



Features

- Improved ruggedness $V_{(BR)DSS} > 200 \text{ V}$
- Excellent thermal stability
- 20:1 all phases load mismatch capability
- $P_{OUT} = 150 \text{ W min. with } 14.8 \text{ dB gain @ } 175 \text{ MHz}$
- In compliance with the 2002/95/EC European directive

Description

The SD4931 is an N-channel MOS field-effect RF power transistor. It is intended for use in 50 V DC large signal applications up to 250 MHz.

Table 1. Device summary

| Order code | Marking | Base qty. | Package | Packaging ⁽¹⁾ |
|------------|-----------------------|-----------|---------|--------------------------|
| SD4931 | SD4931 ⁽¹⁾ | 25 pcs | M174 | Plastic tray |

1. For more details please refer to [Chapter 5: Marking, packing and shipping specifications](#).

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1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25\text{ °C}$)

| Symbol | Parameter | Value | Unit |
|---------------|----------------------------------------------------|-------------|--------------------|
| $V_{(BR)DSS}$ | Drain source voltage | 200 | V |
| V_{DGR} | Drain-gate voltage ($R_{GS} = 1\text{ M}\Omega$) | 200 | V |
| V_{GS} | Gate-source voltage | ± 20 | V |
| I_D | Drain current | 20 | A |
| P_{DISS} | Power dissipation | 389 | W |
| T_J | Max. operating junction temperature | 200 | $^{\circ}\text{C}$ |
| T_{STG} | Storage temperature | -65 to +150 | $^{\circ}\text{C}$ |

1.2 Thermal data

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|------------|------------------------------------|-------|-----------------------------|
| R_{thJC} | Junction - case thermal resistance | 0.45 | $^{\circ}\text{C}/\text{W}$ |

2 Electrical characteristics

$$T_{\text{CASE}} = +25\text{ }^{\circ}\text{C}$$

2.1 Static

Table 4. Static

| Symbol | Test conditions | | Min | Typ | Max | Unit |
|-----------------------------|-------------------------------|---------------------------------|-----|-----|-----|------|
| $V_{(\text{BR})\text{DSS}}$ | $V_{\text{GS}} = 0\text{ V}$ | $I_{\text{DS}} = 100\text{ mA}$ | 200 | | | V |
| I_{DSS} | $V_{\text{GS}} = 0\text{ V}$ | $V_{\text{DS}} = 100\text{ V}$ | | | 1 | mA |
| I_{GSS} | $V_{\text{GS}} = 20\text{ V}$ | $V_{\text{DS}} = 0\text{ V}$ | | | 250 | nA |
| $V_{\text{GS(Q)}}$ | $V_{\text{DS}} = 10\text{ V}$ | $I_{\text{D}} = 250\text{ mA}$ | 1.5 | 2.5 | 4.0 | V |
| $V_{\text{DS(ON)}}$ | $V_{\text{GS}} = 10\text{ V}$ | $I_{\text{D}} = 10\text{ A}$ | | 3.5 | 5.0 | V |
| G_{FS} | $V_{\text{DS}} = 10\text{ V}$ | $I_{\text{D}} = 2.5\text{ A}$ | 2.5 | 4.0 | | S |
| C_{ISS} | $V_{\text{GS}} = 0\text{ V}$ | $V_{\text{DS}} = 50\text{ V}$ | | 500 | | pF |
| C_{OSS} | $V_{\text{GS}} = 0\text{ V}$ | $V_{\text{DS}} = 50\text{ V}$ | | 200 | | pF |
| C_{RSS} | $V_{\text{GS}} = 0\text{ V}$ | $V_{\text{DS}} = 50\text{ V}$ | | 8 | | pF |

2.2 Dynamic

Table 5. Dynamic

| Symbol | Test conditions | | Min | Typ | Max | Unit |
|------------------|-------------------------------|----------------------------------------------------------------------------------------------------------|------|------|-----|------|
| $P_{1\text{dB}}$ | $V_{\text{DD}} = 50\text{ V}$ | $I_{\text{DQ}} = 250\text{ mA}$ $f = 175\text{ MHz}$ | 150 | 175 | | W |
| G_{PS} | $V_{\text{DD}} = 50\text{ V}$ | $I_{\text{DQ}} = 250\text{ mA}$ $P_{\text{OUT}} = 150\text{ W}$ $f = 175\text{ MHz}$ | 13 | 14.8 | | dB |
| n_{D} | $V_{\text{DD}} = 50\text{ V}$ | $I_{\text{DQ}} = 250\text{ mA}$ $P_{\text{OUT}} = 150\text{ W}$ $f = 175\text{ MHz}$ | 50 | 56 | | % |
| Load mismatch | $V_{\text{DD}} = 50\text{ V}$ | $I_{\text{DQ}} = 250\text{ mA}$ $P_{\text{OUT}} = 150\text{ W}$ $f = 175\text{ MHz}$ All phase angles | 10:1 | 20:1 | | VSWR |

3 Typical performance

Figure 2. Transient thermal impedance

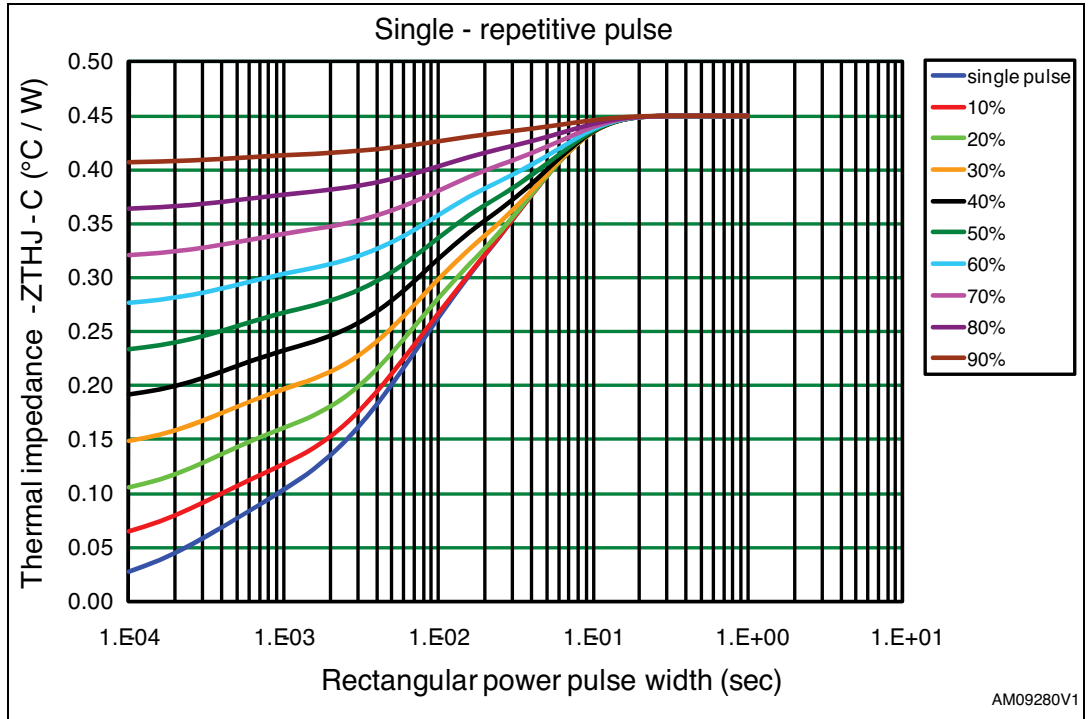


Figure 3. Transient thermal impedance model

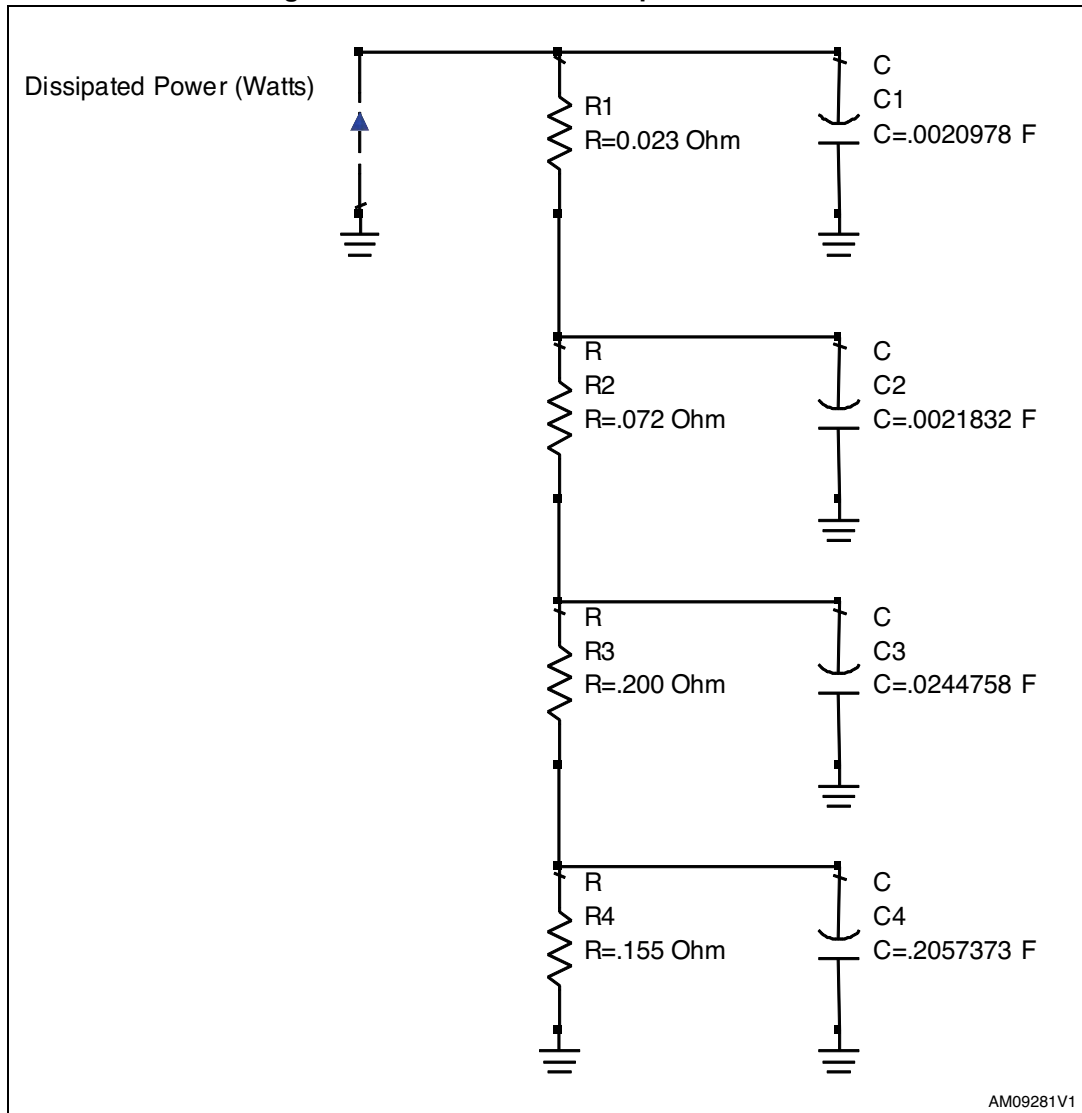


Figure 4. Power gain and efficiency vs output power_Vdd = 50 V, Idq = 250 mA, Freq = 175 MHz

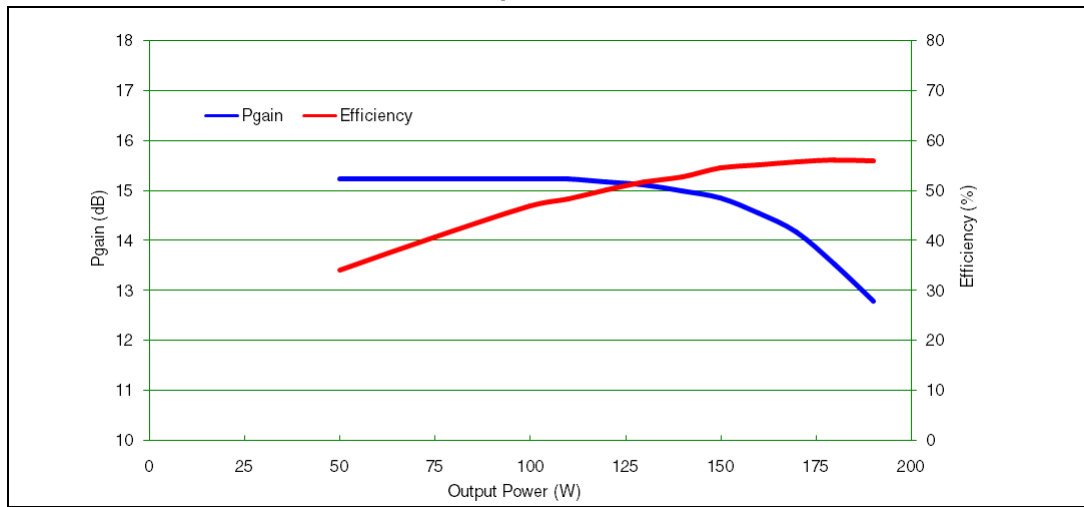


Table 6. Vgs sort (@250 mA)

| Marking | Min. | Max. |
|---------|------|------|
| DD | 1.5 | 1.6 |
| EE | 1.6 | 1.7 |
| FF | 1.7 | 1.8 |
| A | 1.8 | 1.9 |
| B | 1.9 | 2 |
| C | 2 | 2.1 |
| D | 2.1 | 2.2 |
| E | 2.2 | 2.3 |
| F | 2.3 | 2.4 |
| G | 2.4 | 2.5 |
| H | 2.5 | 2.6 |
| I | 2.6 | 2.7 |
| J | 2.7 | 2.8 |
| K | 2.8 | 2.9 |
| L | 2.9 | 3 |
| M | 3 | 3.1 |
| N | 3.1 | 3.2 |
| O | 3.2 | 3.3 |
| P | 3.3 | 3.4 |
| Q | 3.4 | 3.5 |

Table 6. Vgs sort (@250 mA) (continued)

| Marking | Min. | Max. |
|---------|------|------|
| R | 3.5 | 3.6 |
| S | 3.6 | 3.7 |
| T | 3.7 | 3.8 |
| U | 3.8 | 3.9 |
| V | 3.9 | 4 |

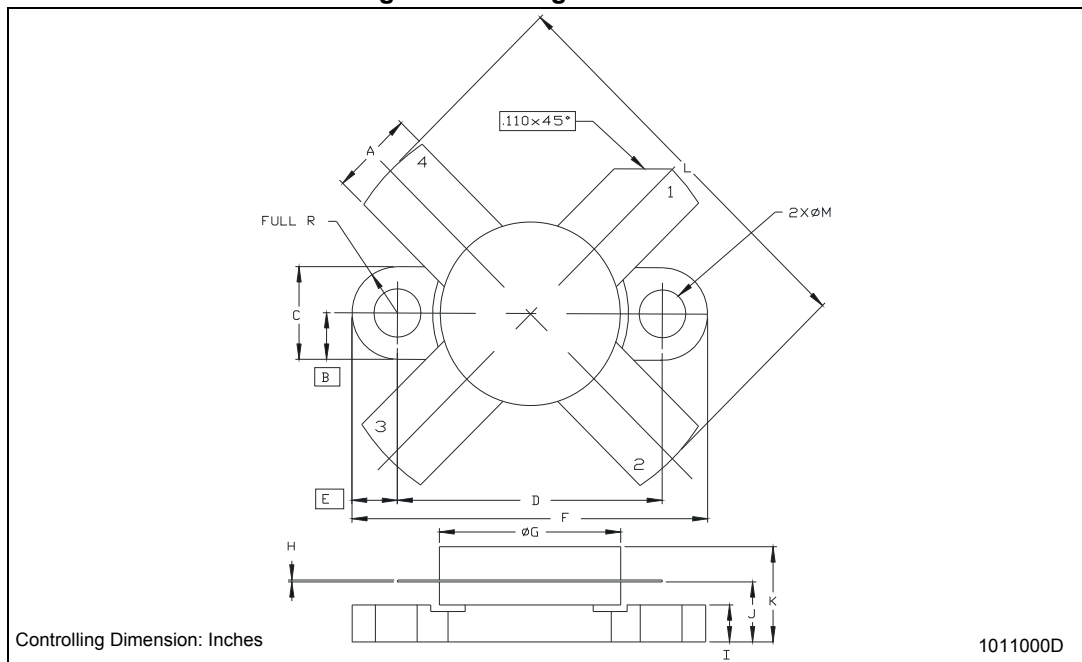
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 7. M174 (0.500 DIA 4/L N/HERM W/FLG) mechanical data

| Dim. | mm. | | | Inch | | |
|------|-------|------|-------|-------|-------|-------|
| | Min | Typ | Max | Min | Typ | Max |
| A | 5.56 | | 5.584 | 0.219 | | 0.230 |
| B | | 3.18 | | | 0.125 | |
| C | 6.22 | | 6.48 | 0.245 | | 0.255 |
| D | 18.28 | | 18.54 | 0.720 | | 0.730 |
| E | | 3.18 | | | 0.125 | |
| F | 24.64 | | 24.89 | 0.970 | | 0.980 |
| G | 12.57 | | 12.83 | 0.495 | | 0.505 |
| H | 0.08 | | 0.18 | 0.003 | | 0.007 |
| I | 2.11 | | 3.00 | 0.083 | | 0.118 |
| J | 3.81 | | 4.45 | 0.150 | | 0.175 |
| K | | | 7.11 | | | 0.280 |
| L | 25.53 | | 26.67 | 1.005 | | 1.050 |
| M | 3.05 | | 3.30 | 0.120 | | 0.130 |

Figure 5. Package dimensions



5 Marking, packing and shipping specifications

Table 8. Packing and shipping specifications

| Order code | Packaging | Pcs per tray | Dry pack humidity | Vgs sort | Lot code |
|------------|--------------|--------------|-------------------|-----------|-----------|
| SD4931 | Plastic tray | 25 | < 10% | Not mixed | Not mixed |

Figure 6. Marking layout

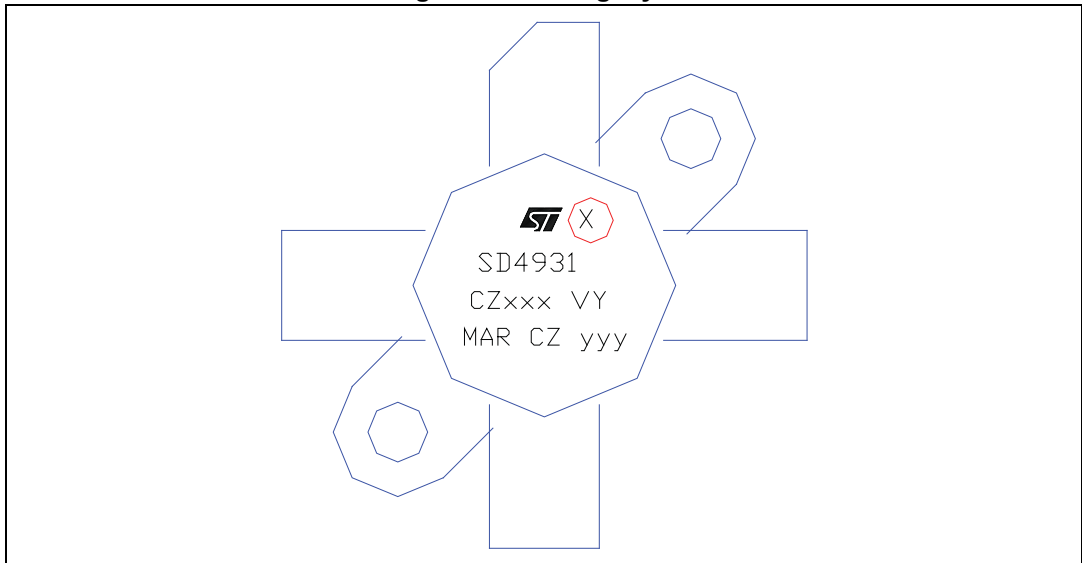


Table 9. Marking specifications

| Symbol | Description |
|--------|--------------------------------|
| X | V _{GS} sort |
| CZ | Assembly plant |
| xxx | Last 3 digits of diffusion lot |
| VY | Diffusion plant |
| MAR | Country of origin |
| CZ | Test and finishing plant |
| y | Assembly year |
| yy | Assembly week |

6 Revision history

Table 10. Document revision history

| Date | Revision | Changes |
|-------------|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 17-Mar-2008 | 1 | Initial release. |
| 14-Jan-2010 | 2 | Updated test conditions in Table 5: Dynamic . |
| 23-May-2011 | 3 | Inserted Figure 2: Transient thermal impedance , Figure 3: Transient thermal impedance model and Section 5: Marking, packing and shipping specifications . |
| 10-Jun-2013 | 4 | <ul style="list-style-type: none">– Modified document title to “HF/VHF/UHF RF power N-channel MOSFET”– Corrected error in $V_{GS(Q)}$ symbol and test conditions in Table 4: Static.– Minor text edits. |

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